Accepted Manuscript

Photocatalytic properties of intrinsically defective undoped bismuth vanadate (BiVO4) photocatalyst: A DFT study

Journal of Electroanalytical Chemistry

**The Committee of the Committee o

Mahesh Datt Bhatt, Jin Yong Lee

PII: S1572-6657(18)30639-8

DOI: doi:10.1016/j.jelechem.2018.09.042

Reference: JEAC 12625

To appear in: Journal of Electroanalytical Chemistry

Received date: 22 June 2018

Revised date: 19 September 2018 Accepted date: 20 September 2018

Please cite this article as: Mahesh Datt Bhatt, Jin Yong Lee , Photocatalytic properties of intrinsically defective undoped bismuth vanadate (BiVO4) photocatalyst: A DFT study. Jeac (2018), doi:10.1016/j.jelechem.2018.09.042

This is a PDF file of an unedited manuscript that has been accepted for publication. As a service to our customers we are providing this early version of the manuscript. The manuscript will undergo copyediting, typesetting, and review of the resulting proof before it is published in its final form. Please note that during the production process errors may be discovered which could affect the content, and all legal disclaimers that apply to the journal pertain.

ACCEPTED MANUSCRIPT

Photocatalytic Properties of Intrinsically Defective Undoped Bismuth Vanadate (BiVO₄) Photocatalyst: A DFT Study

Mahesh Datt Bhatt and Jin Yong Lee*

Department of Chemistry, Sungkyunkwan University, Suwon 16419, Korea

Abstract

Monoclinic clinobisvanite BiVO₄ is one of the most promising photocatalyst due to its stability, low cost, narrow band gap, and suitable valence band maximum (VBM) position. The valence band maximum of about -7.10 eV at vacuum level was observed, which is well below the redox potential of water. However, the conduction band minimum, CBM of about -4.86 eV at vacuum level, which was responsible for its low efficiency. The presence of metal (Bi or V) vacancy changed the charge density and VBM of pristine BiVO₄. Our calculated results revealed that 0.04% of the intrinsic Bi or V defects enhanced p-type conductivity and hence improved photocatalytic activity than O-interstitial in pristine BiVO₄. The optical properties of both pristine and intrinsically defective BiVO₄ were calculated and analyzed with perspective of their photocatalytic properties. Conclusively, the role of Bi or V (metal) vacancies in pristine BiVO₄ was found to be significant than O interstitials in enhancing the photocatalytic properties regarding the solar water splitting.

Keywords: BiVO4, doping, vacancies, water splitting, conductivity, DFT

Download English Version:

https://daneshyari.com/en/article/10225198

Download Persian Version:

https://daneshyari.com/article/10225198

<u>Daneshyari.com</u>